Diode Module

# **STARPOWER**

SEMICONDUCTOR

## FD600HFE170C2S

**Molding Type Module** 

1700V/600A 2 in one-package

### **General Description**

STARPOWER Diode Power Module provides low forward voltage as well as low reverse recovery loss. They are designed for the applications such as SMPS.

#### Features

- Fast soft diode
- Low forward voltage drop
- Small temperature coefficient
- Low reverse recovery losses
- High ruggedness
- Low inductance
- Isolated copper baseplate using DBC technology

## **Typical Applications**

- SMPS
- PFC
- Electric welders
- DC choppers

### **Equivalent Circuit Schematic**





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# FRED

Symbol	Description	Value	Unit
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	1700	V
I <sub>F</sub>	Continuous Forward Current	600	Α
I <sub>FRM</sub>	Repetitive Peak Forward Current	1200	Α
P <sub>D</sub>	Maximum Power Dissipation @ T <sub>i</sub> =175°C	1829	W
T <sub>jmax</sub>	Maximum Junction Temperature	175	°C
T <sub>jop</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature Range	-40 to +125	°C
V <sub>ISO</sub>	Isolation Voltage RMS,f=50Hz,t=1min	4000	V

#### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

#### Electrical Characteristics of Diode T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>F</sub>	Diada Forward	$I_{\rm F}$ =600A, $T_{\rm i}$ =25°C		1.80	2.25	
	Voltage	$I_{\rm F}$ =600A, $T_{\rm j}$ =125°C		1.90		V
		$I_{\rm F}$ =600A, $T_{\rm j}$ =150°C		1.95		
Qr	Recovered			150		μC
		$I_{\rm F}=600{\rm A}, V_{\rm R}=900{\rm V}$				•
I <sub>RM</sub>	Peak Reverse	-di/dt=5200A/µs		640		А
	Recovery Current	$T_i=25^{\circ}C$				
Erec	Reverse Recovery	5		85.0		mJ
	Energy					
Qr	Recovered			250		μC
	Charge	$I_{F}=600A, V_{R}=900V$ -di/dt=5200A/µs $T_{j}=125^{\circ}C$				•
I <sub>RM</sub>	Peak Reverse			700		А
	Recovery Current					
E <sub>rec</sub>	Reverse Recovery			145		mJ
	Energy			_	<u> </u>	
Qr	Recovered	$I_F=600A, V_R=900V$ -di/dt=5200A/µs $T_j=150^{\circ}C$		275		uС
	Charge					P* -
I <sub>RM</sub>	Peak Reverse			715		А
	Recovery Current			, 10	<u> </u>	**
E <sub>rec</sub>	Reverse Recovery			160		mI
	Energy			100		1115

#### **Thermal Characteristics**

Symbol	Parameter	Min.	Тур.	Max.	Unit
L <sub>CE</sub>	Stray Inductance			20	nH
R <sub>CC'+EE'</sub>	Module Lead Resistance, Terminal to Chip		0.35		mΩ
R <sub>thJC</sub>	Junction-to-Case (per Diode)			0.082	K/W
R <sub>thCH</sub>	Case-to-Heatsink (per Module)		0.035		K/W
М	Terminal Connection Torque, Screw M6	2.5		5.0	N.m
	Mounting Torque, Screw M6	3.0		5.0	
G	Weight of Module		300		g

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#### **Equivalent Circuit Schematic**



### **Package Dimensions**

Dimensions in Millimeters





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